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Bib Data Sheet

CONFIRMATION NO. 1610

<b>SERIAL NUMBER</b> 09/881,782	<b>FILING DATE</b> 06/18/2001 <b>RULE</b>	<b>CLASS</b> 313	<b>GROUP ART UNIT</b> 2879	<b>ATTORNEY DOCKET NO.</b> Q61741
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**APPLICANTS**  
Takashi Udagawa, Saitama, JAPAN;

**\*\* CONTINUING DATA \*\*\*\*\***  
THIS APPLN CLAIMS BENEFIT OF 60/248,011 11/14/2000 *yes*

**\*\* FOREIGN APPLICATIONS \*\*\*\*\***  
JAPAN P2000-185554 06/21/2000 *yes*  
JAPAN P2001-116251 04/16/2001

**IF REQUIRED, FOREIGN FILING LICENSE GRANTED**  
\*\* 08/06/2001

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY JAPAN	SHEETS DRAWING 6	TOTAL CLAIMS 20	INDEPENDENT CLAIMS 3
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met and no				
Verified and Acknowledged Examiner's Signature <i>[Signature]</i> Initials <i>[Initials]</i>				

**ADDRESS**  
SUGHRUE, MION, ZINN, MACPEAK & SEAS, PLLC  
2100 Pennsylvania Avenue, N.W.  
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**TITLE**  
Group-III nitride semiconductor light-emitting diode, light-emitting diode lamp, light source, electrode for group-III nitride semiconductor light-emitting diode, and method for producing the electrode

<b>FILING FEE RECEIVED</b> 1232	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees ( Filing ) <input type="checkbox"/> 1.17 Fees ( Processing Ext. of time ) <input type="checkbox"/> 1.18 Fees ( Issue ) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit
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